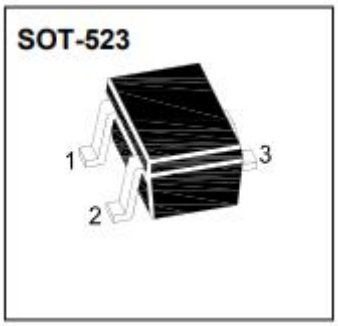
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BAT54T/AT/ST/CT

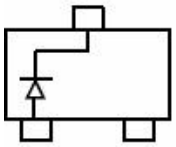
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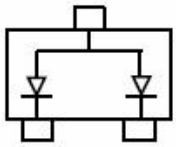


FEATURES

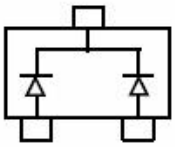
Extremely Fast Switching Speed



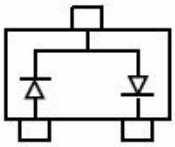
BAT54T MARKING: KL1



BAT54AT MARKING: KL2



BAT54CT MARKING: KL3



BAT54ST MARKING: KL4

Maximum Ratings @T_A=25℃

Parameter	Symbol	Limits	Unit
Peak Repetitive Peak reverse voltage **Working Peak Reverse Voltage**	V_{RRM} V_{RWM} V_R	30	V
Forward Continuous Current	I_{FM}	200	mA
Power Dissipation	P_D	150	mW
Storage temperature	T_{STG}	-55-150	℃

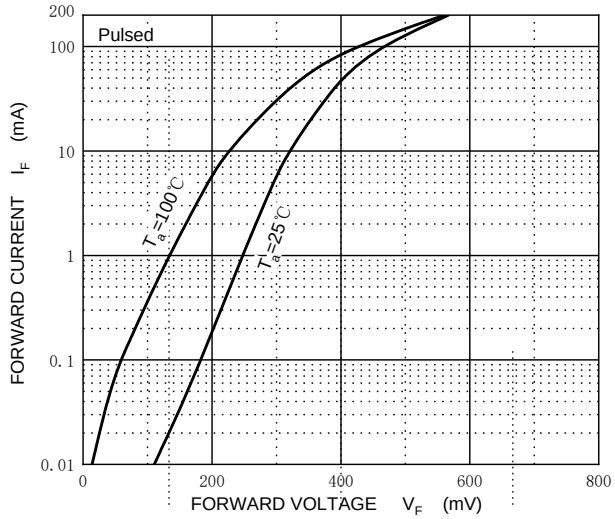
Electrical Characteristics @T_A=25℃

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	$V_{(BR)R}$	30			V	IR=100μA
Forward voltage	V_{F1}			0.24	V	I_F=0.1mA
	V_{F2}			0.32	V	I_F=1mA
	V_{F3}			0.40	V	I_F=10mA
	V_{F4}			0.50	V	I_F=30mA
	V_{F5}			1	V	I_F=100mA
Reverse current	I_R			2	μA	V_R=25V
Diode Capacitance	C_D			15	pF	V_R=1V,f=1MHz
Reverse Recovery Time	t_{rr}			5	nS	I_F=I_R=10mA Irr=0.1XI_R,R_L=100Ω

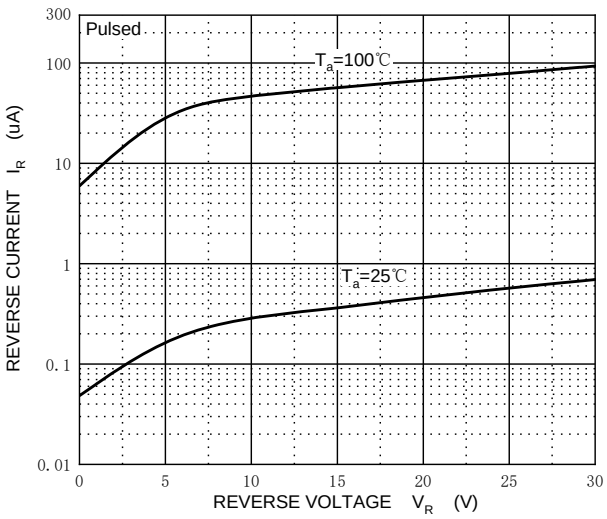
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Typical Characteristics

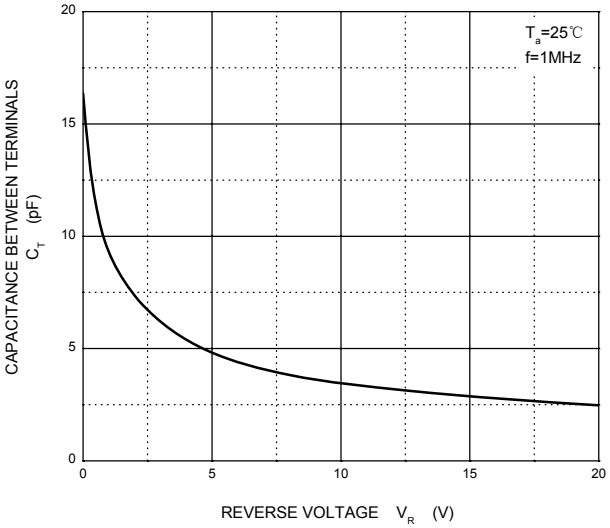
Forward Characteristics



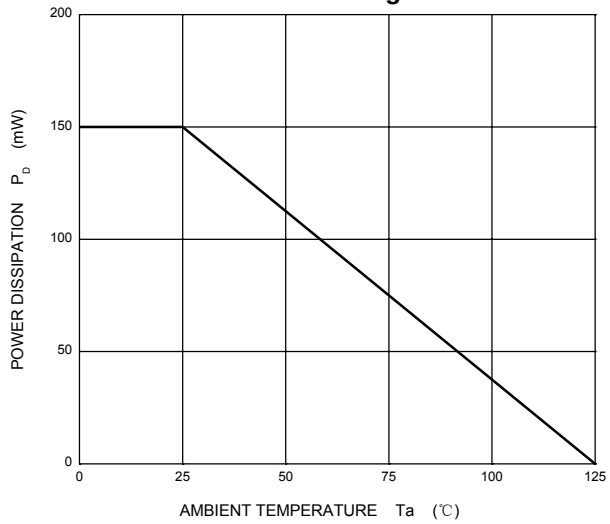
Reverse Characteristics



Capacitance Characteristics



Power Derating Curve



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